## Datasheet

# ROHM

# SiC Schottky Barrier Diode

| $V_R$          | 650V |
|----------------|------|
| I <sub>F</sub> | 15A  |
| $Q_{C}$        | 37nC |

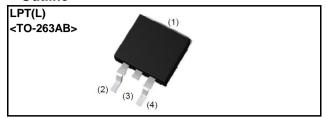
#### Features

- 1) Low forward voltage
- 2) Negligible recovery time/current
- 3) Temperature independent switching behavior
- 4) High surge current capability
- 5) Low leakage current

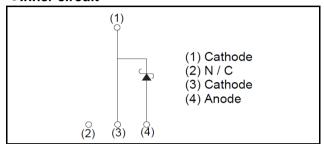
# Applications

- Switch Mode Power Supply
- Uninterruptible Power Supply
- ·Solar Inverter
- Motor Drive
- Air Conditioner
- •EV Charger

#### Outline



#### •Inner circuit



Packaging specifications

|       | <u>gg -pa</u>             |               |
|-------|---------------------------|---------------|
|       | Packaging                 | Embossed tape |
|       | Reel size (mm)            | 330           |
| Turno | Tape width (mm)           | 24            |
| Туре  | Basic ordering unit (pcs) | 1.000         |
|       | Packing code              | TLL           |
|       | Marking                   | SCS315AJ      |

# ● Absolute maximum ratings (T<sub>i</sub> = 25°C)

| Parameter                       |   | Symbol           | Value             | Unit             |
|---------------------------------|---|------------------|-------------------|------------------|
| Reverse voltage (re             | petitive peak)                            | $V_{RM}$         | 650               | V                |
| Reverse voltage (D0             | C)  | V <sub>R</sub>   | 650               | V                |
| Continuous forward              | current (T <sub>c</sub> = 130°C)          | I <sub>F</sub>   | 15                | А                |
| Surge non-                      | PW=10ms sinusoidal, T <sub>j</sub> =25°C  |                  | 112               | А                |
| repetitive forward              | PW=10ms sinusoidal, T <sub>j</sub> =150°C | I <sub>FSM</sub> | 95                | А                |
| current                         | PW=10μs square, T <sub>j</sub> =25°C      |                  | 410               | А                |
| Repetitive peak forward current |   | I <sub>FRM</sub> | 66 *1             | А                |
| 1≦PW≦10ms, T <sub>j</sub> =25°C |   | ∫ i²dt           | 62                | A <sup>2</sup> s |
| i <sup>2</sup> t value          | 1≦PW≦10ms, T <sub>j</sub> =150°C          | J i⁻at           | 45                | A <sup>2</sup> s |
| Total power disspation          |   | P <sub>D</sub>   | 100 <sup>*2</sup> | W                |
| Junction temperature            |   | T <sub>j</sub>   | 175               | °C               |
| Range of storage temperature    |   | $T_{stg}$        | -55 to +175       | °C               |

<sup>\*1</sup> T<sub>c</sub>=100°C, T<sub>i</sub>=150°C, Duty cycle=10% \*2 T<sub>c</sub>=25°C

# ●Electrical characteristics (T<sub>i</sub> = 25°C)

| Parameter                          | Symbol           | Conditions                                 | Values |       |      | Lloit |
|------------------------------------|------------------|--|--------|-------|------|-------|
|                                    |                  |  | Min.   | Тур.  | Max. | Unit  |
| DC blocking voltage                | $V_{DC}$         | I <sub>R</sub> =75μA                       | 650    | -     | -    | V     |
|                                    | V <sub>F</sub>   | I <sub>F</sub> =15A,T <sub>j</sub> =25°C   | -      | 1.35  | 1.50 | V     |
| Forward voltage                    |                  | I <sub>F</sub> =15A,T <sub>j</sub> =150°C  | -      | 1.44  | 1.71 | V     |
|                                    |                  | I <sub>F</sub> =15A,T <sub>j</sub> =175°C  | -      | 1.50  | -    | V     |
| Reverse current                    | I <sub>R</sub>   | V <sub>R</sub> =650V,T <sub>j</sub> =25°C  | -      | 0.045 | 75   | μΑ    |
|                                    |                  | V <sub>R</sub> =650V,T <sub>j</sub> =150°C | -      | 3     | 300  | μΑ    |
|                                    |                  | V <sub>R</sub> =650V,T <sub>j</sub> =175°C | -      | 9     | -    | μΑ    |
| Total capacitance                  | С                | V <sub>R</sub> =1V,f=1MHz                  | -      | 750   | -    | pF    |
|                                    |                  | V <sub>R</sub> =650V,f=1MHz                | -      | 68    | -    | pF    |
| Total capacitive charge            | Q <sub>C</sub>   | V <sub>R</sub> =400V,di/dt=350A/μs         | -      | 37    | -    | nC    |
| Switching time                     | t <sub>C</sub>   | V <sub>R</sub> =400V,di/dt=350A/μs         | -      | 21    | -    | ns    |
| Non-repetetive<br>Avaranche Energy | E <sub>ava</sub> | L=1mH                                      | -      | 210   | -    | mJ    |

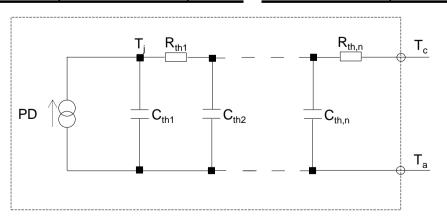
# Thermal characteristics

| Parameter          | Symbol               | Conditions | Values |      |      | Unit  |
|--------------------|----------------------|------------|--------|------|------|-------|
|                    |                      |            | Min.   | Тур. | Max. | Offic |
| Thermal resistance | R <sub>th(j-c)</sub> | -          | -      | 1    | 1.5  | °C/W  |

# ●Typical Transient Thermal Characteristics

| Symbol           | Value    | Unit |
|------------------|----------|------|
| R <sub>th1</sub> | 1.34E-01 |      |
| R <sub>th2</sub> | 8.63E-01 | K/W  |
| R <sub>th3</sub> | 1.00E-03 |      |

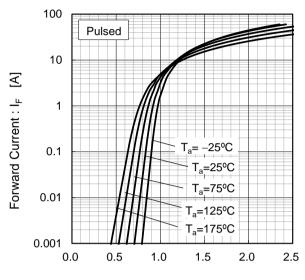
| Symbol           | Value    | Unit |
|------------------|----------|------|
| C <sub>th1</sub> | 2.82E-04 |      |
| C <sub>th2</sub> | 3.73E-03 | Ws/K |
| C <sub>th3</sub> | 4.35E+00 |      |



1.000

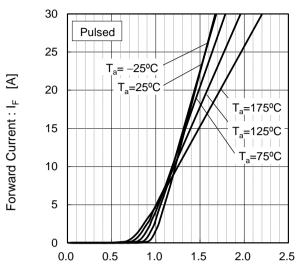
#### •Electrical characteristic curves

Fig.1 V<sub>F</sub> - I<sub>F</sub> Characteristics



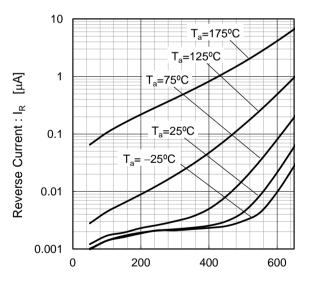
Forward Voltage : V<sub>F</sub> [V]

Fig.2 V<sub>F</sub> - I<sub>F</sub> Characteristics



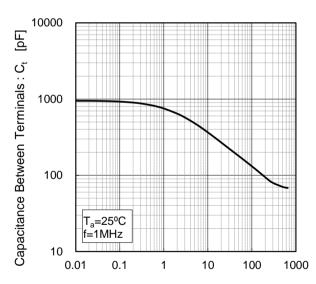
Forward Voltage : V<sub>F</sub> [V]

Fig.3  $V_R$  -  $I_R$  Characteristics



Reverse Voltage : V<sub>R</sub> [V]

Fig.4 V<sub>R</sub>-C<sub>t</sub> Characteristics



Reverse Voltage : V<sub>R</sub> [V]

#### Electrical characteristic curves

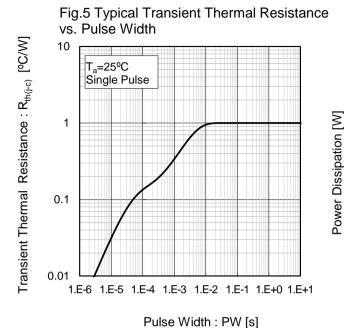


Fig.6 Power Dissipation

120
100
80
60
40
20
25 50 75 100 125 150 175

Case Temperature : T<sub>c</sub> [°C]

Fig.7\*3 Maximum peak forward current derating curve I<sub>P</sub> - T<sub>c</sub> 180 160 Peak Forward Current: Ip [A] 140 120 Duty=0.1 100 Duty=0.2 80 60 Duty=0.5 40 20 Duty=0.8 D.C 0 25 50 75 100 125 150 175

Case Temperature : T<sub>c</sub> [°C]
\*3 Based on max Vf, max R<sub>th(j-c)</sub>
Valid for switching of above 10kHz, excluding D.C. curve.

Fig.8\*4 Typical peak forward current derating curve I<sub>P</sub> - T<sub>c</sub> (Not guaranteed) 180 160 Duty=0.1 140 120 Duty=0.2 100 80 Duty=0.5 60 40 Duty=0.8 20 D.C. 0 25 50 75 100 125 150 175

> Case Temperature : T<sub>c</sub> [°C] \*4 Based on typ Vf, typ R<sub>th(j-c)</sub> Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

Peak Forward Current : Ip [A]

#### Electrical characteristic curves

# Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)

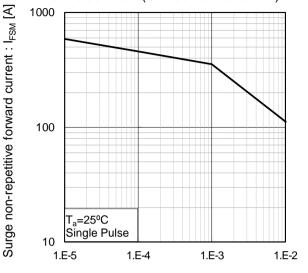
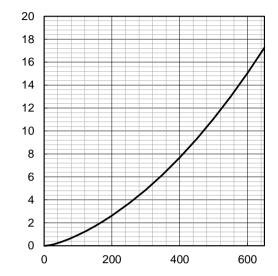


Fig.10 Typical capacitance store energy



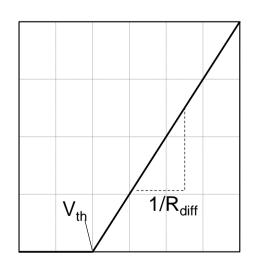
Capacitance stored energy :  $E_C[\mu J]$ 

Reverse Voltage : V<sub>R</sub> [V]

## Symplified forward characteristic model

Fig.11 Equivalent forward current curve

Pulse Width: PW [s]



Forward Voltage: V<sub>F</sub>

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th} \left( \ T_{j} \ \right) = a_{0} + a_{1} \, T_{j} \\ &R_{diff} \left( \ T_{j} \ \right) = b_{0} + b_{1} \, T_{j} + b_{2} \, T_{j}^{2} \end{aligned}$$

| Symbol                | Typical Value | Unit              |
|-----------------------|---------------|-------------------|
| <b>a</b> <sub>0</sub> | 9.66E-01      | V                 |
| a <sub>1</sub>        | -1.10E-03     | V/°C              |
| b <sub>0</sub>        | 2.35E-02      | Ω                 |
| b <sub>1</sub>        | 4.97E-05      | Ω/°C              |
| b <sub>2</sub>        | 5.12E-07      | Ω/°C <sup>2</sup> |

 $T_i \text{ in } {}^{\circ}\text{C}; -55 {}^{\circ}\text{C} < T_i < 175 {}^{\circ}\text{C}; I_F < 30 \text{ A}$ 

Forward Current: IF

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